4 Channel Auto-Bidirectional Multi-Voltage Level Translator for Open-Drain and Push-Pull Applications

General Description

The ETF0104 supports bidirectional voltage translation without the need for DIR pin which minimizes system effort. The ETF0104 supports 5V tolerance on I/O port which makes it compatible with TTL or CMOS levels in industrial and telecom applications. The ETF0104 is able to set up different voltage translation levels which makes it very flexible.

Features

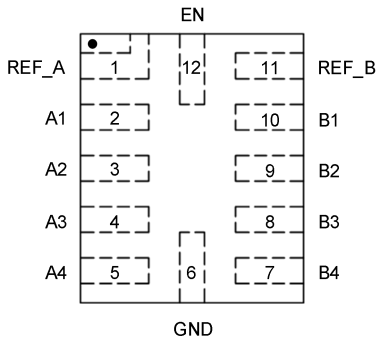
- No Directional Control Required
- Allows Bidirectional Voltage-level Translation Between: 0.95V~3.3V ↔ 1.62V~5.0V
- Low Standby Current
- 5V Tolerance I/O Port to Support TTL or CMOS
- Low R_{ON} Provides Less Signal Distortion
- Flow-through Pin-out for Easy PCB Trace Routing
- Supports up to 40MHz Up/Down Translation with 50pF Load Capacitor
- Extended Temperature Range: -40°C to 85°C
- ESD Protection Complies with JESD22 Standard
  -- HBM: ±2000V Pass (JEDEC JS-001)
  -- CDM: ±1000V Pass (JEDEC JS-002)
- Latch-up Performance Exceeds ±100mA per JEDEC JESD78F
- Part No. and Package Information

Part No.	Package	Packing Option	MSL
ETF0104V	TSSOP14 (5.0mm × 4.4mm)	Tape and Reel, 4K/Reel	3
ETF0104Y1	QFN12 (2.0mm × 1.7mm)	Tape and Reel, 3K/Reel	1
ETF0104Y4	QFN12 (1.6mm × 1.6mm)	Tape and Reel, 3K/Reel	1

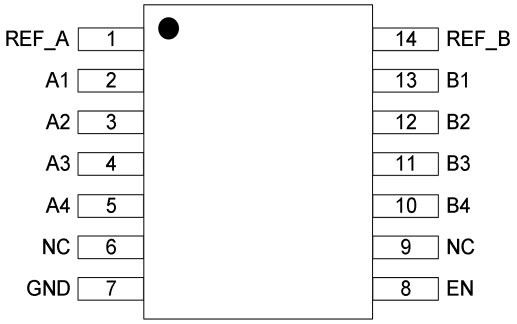
Applications

- I^2C, I^3C, I^2S, SPI, MDIO, DMIC, UART, SDIO, GPIO, and Other Two-signal Interfaces
- Enterprise Systems
- Communications Equipment
- Personal Computers
- Industrial Automation

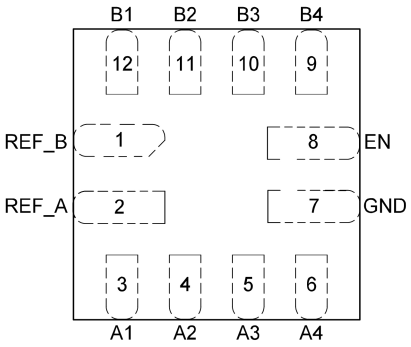
Pin Configuration



ETF0104Y1



ETF0104V



ETF0104Y4

TOP VIEW

Figure 1. Pin Configuration

Pin Function

Pin No.			Pin Name	Pin Function
QFN12(2*1.7)	QFN12(1.6*1.6)	TSSOP14		
6	7	8	GND	Ground
1	2	1	REF_A	Reference Supply Voltage
2~5	3~6	2~5	An	Auto-Bidirectional Data of A Port
7~10	9~12	10~13	Bn	Auto-Bidirectional Data of B Port
11	1	14	REF_B	Reference Supply Voltage
12	8	8	EN	Enable Input
-	-	6,9	NC	Not Connected

Block Diagram

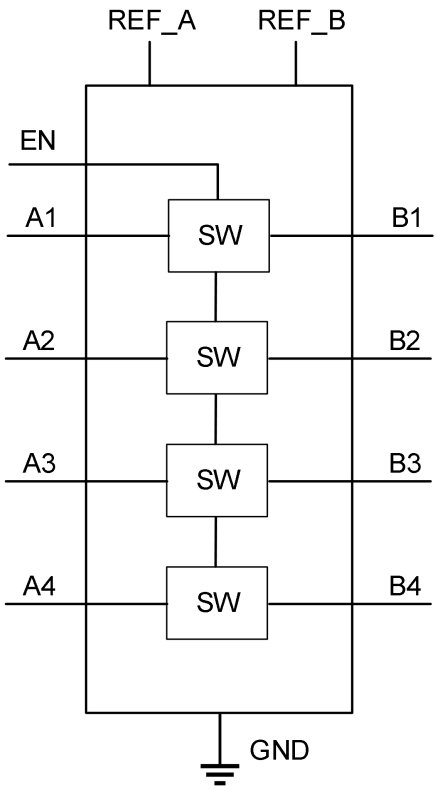


Figure 2. Block Diagram

Functional Description

The ETF0104 can be used in level-translation applications for interfacing devices or systems operating with one another that operate at different interface voltages. The ETF0104 is ideal for use in applications where an open-drain driver is connected to the data I/Os. The ETF0104 can also be used in applications where a push-pull driver is connected to the data I/Os.

Auto Bidirectional Voltage Translation

The device is an auto bidirectional voltage level translator that is operational from 0.95 to 5.5V on REF_A and 1.62 to 5.5V on REF_B. This allows bidirectional voltage translation between 0.95V and 5.5V without the need for a direction pin in open-drain or push-pull applications. Both the output driver of the controller and the peripheral device output can be push-pull or open-drain (pull-up resistors may be required). In both up and down translation, the B-side is often referred to as the high side and refers to devices connected to the B ports. The A-side can be referred to as the low side.

Output Enable

To enable the I/O pins, the EN input can be tied directly to REF_A. To be in the high impedance state during power-up, power-down, or during operation, the EN pin must be LOW. A filter capacitor on REF_B is recommended for a stable supply at the device.

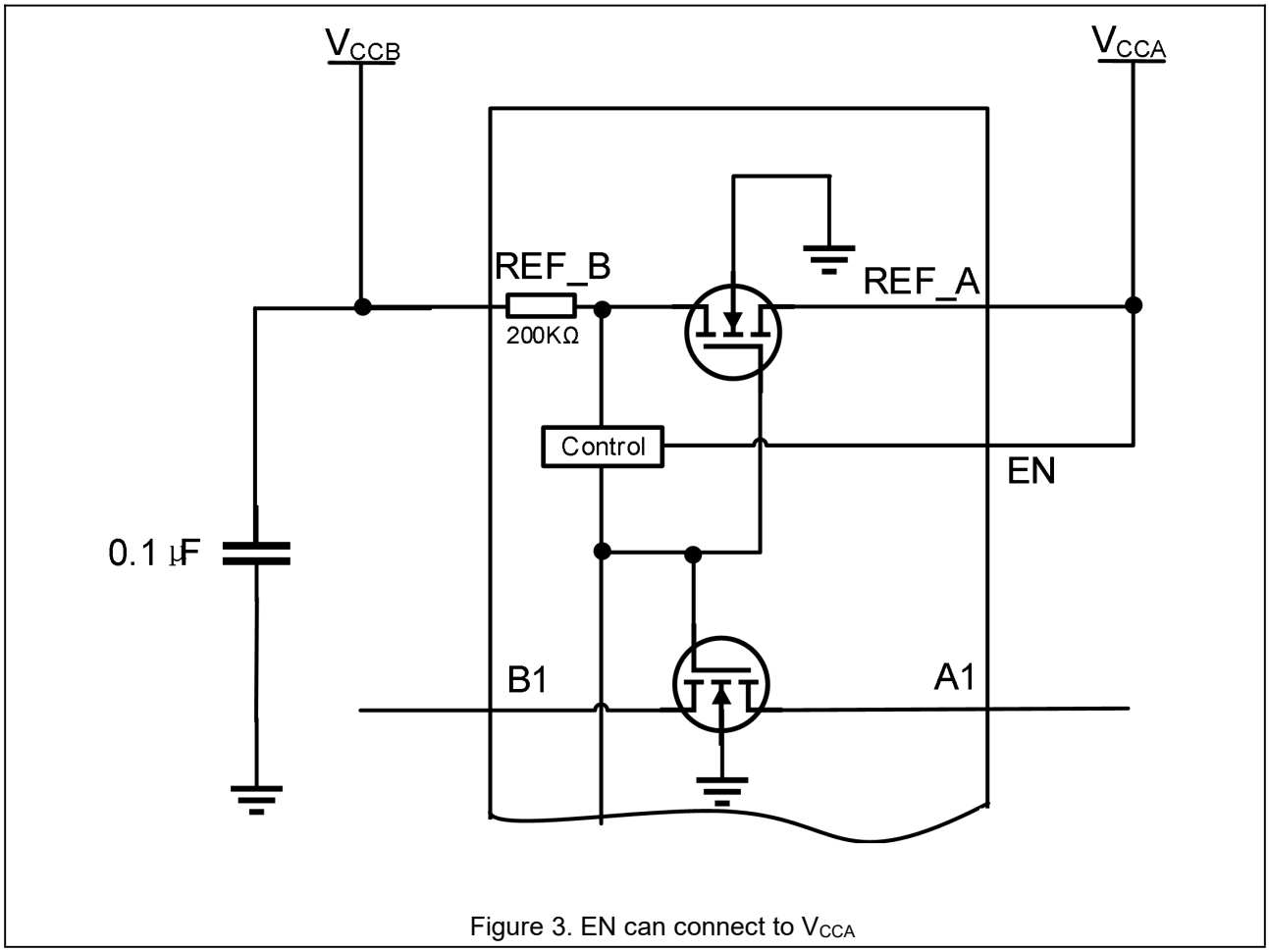


Figure 3. EN can connect to V_{CCA}

The supply voltage of open drain I/O devices can be completely different from the supplies used for the ETF0104 and has no impact on the operation.

Table 1. Enable Pin Function Table

EN PIN	Data Port State
H	An = Bn
L	Hi-Z

Device Functional Modes

For each channel (n), when either the An or Bn port is LOW, the switch provides a low impedance path between the An and Bn ports; the corresponding Bn or An port will be pulled LOW. The low R_{ON} of the switch allows connections to be made with minimal propagation delay and signal distortion. Table 2. provides a summary of device operation

Table 2. Device Functionality

Signal Direction[1]	Input State	Switch State	Functionality
B to A (Down Translation)	B = LOW	ON (Low Impedance)	A-side voltage is pulled low through the switch to the B-side voltage
	B = HIGH	OFF (High Impedance)	A-side voltage is clamped at V_{REF_A} [2]
A to B (Up Translation)	A = LOW	ON (Low Impedance)	B-side voltage is pulled low through the switch to the A-side voltage
	A = HIGH	OFF (High Impedance)	B-side voltage is clamped at V_{REF_A} and then pulled up to the V_{PU} supply voltage

Note 1: The downstream channel should not be actively driven through a low impedance driver, or else bus contention may occur.

Note 2: The A-side can have a pullup to V_{REF_A} for additional current drive capability or may also be pulled above V_{REF_A} with a pullup resistor. Specifications in the Recommended Operating Conditions section should always be followed.

Up Translation

When the signal is being driven from A to B and the An port is HIGH, the switch will be OFF and the Bn port will then be driven to a voltage higher than Vref_A by the pull-up resistor that is connected to the pull-up supply voltage (V_{PU}). This functionality allows seamless translation between higher and lower voltages selected by the user, without the need for directional control. Pull-up resistors are always required on the high side, and pull-ups are only required on the low side, if the low side of the device's output is open drain or its input has a leakage greater than 1μA.

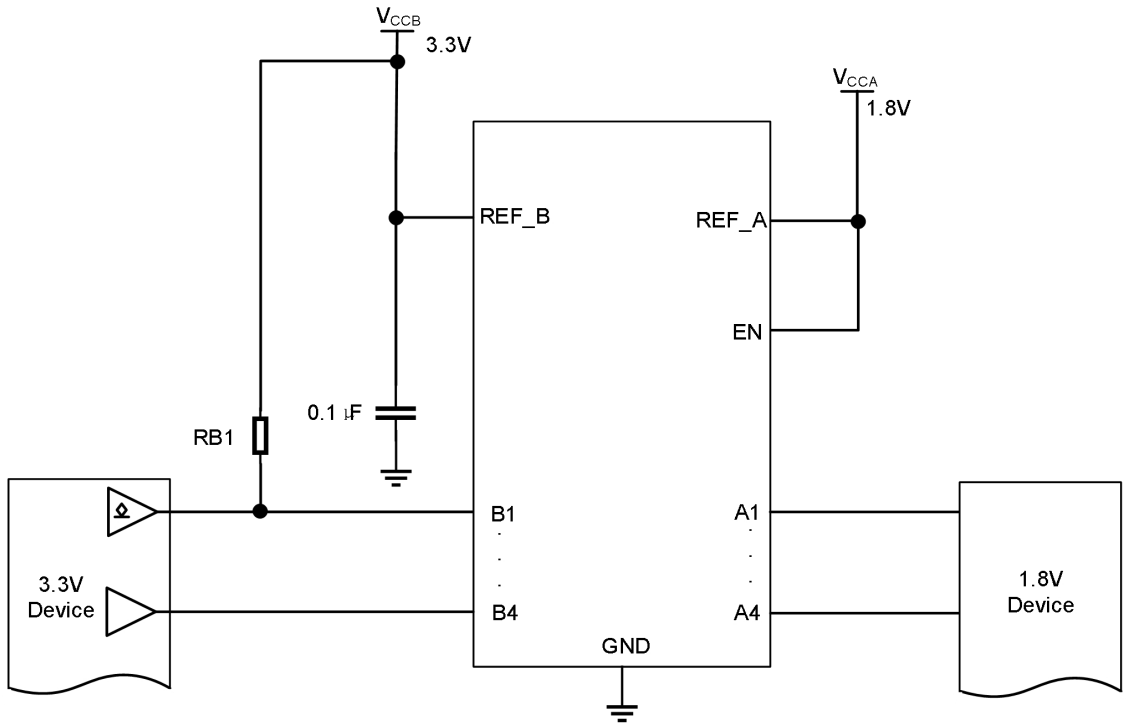


Figure 4. Up Translation Example Schematic with Push-Pull and Open Drain Configuration

Up translation with the ETF0104 requires attention to two important factors: maximum data rate and sink current. Maximum data rate is directly related to the rising edge of the output signal. Sink current depends on supply values and the chosen pull-up resistor values. Equation 1 shows the maximum data rate formula and Equation 2 shows the maximum sink current formula, both of which are estimations. A low RC value is needed to reach high speeds, which also require strong drivers.

$$\frac{1}{3\times 2R_{B1}C_{B1}} \equiv \frac{1}{6R_{B1}C_{B1}}\left(\frac{\text{bits}}{\text{second}}\right) \quad (1)$$

$$I_{OL} \cong \frac{VCCA}{R_{A1}} + \frac{VCCB}{R_{B1}}(A) \quad (2)$$

Down Translation

When the signal is being driven HIGH from the Bn port to An port, the switch will be OFF, clamping the voltage on the An port to the voltage set by V_{REF_A}. A pull-up resistor can be added on either side of the device. There are special circumstances that allow the removal of one or both of the pull-up resistors. If the signal is always going to be down translated from a push-pull transmitter, then the resistor on the B-side can be removed. If the leakage current into the receiver on the A-side is less than 1µA, then the resistor on the A-side can also be removed. This arrangement with no external pull-up resistors can be used when down translating from a push-pull output to a low-leakage input. For an open drain transmitter, the pull-up resistor on the B-side is necessary because an open drain output can't drive high by itself.

Absolute Maximum Ratings

Symbol	Parameters (Items)	Value	Unit
V_I	Input Voltage (REF_A, REF_B, EN)	-0.3 to 6.0	V
$V_{I/O}$	Input/Output Voltage	-0.3 to 6.0	V
I_O	Continuous Channel Current	0 to 100	mA
I_{IK}	Input Clamp Current	-50	mA
T_{STG}	Storage Temperature Range	-65 to +150	ºC
T_J	Operating Junction Temperature	-40 to +150	ºC
V_{ESD}	Human Body Mode[3]	±2000	V
	Charged Device Mode[4]	±1000	V
Latch-up	Latch-up Current[5]	±100	mA

Note3: HBM tested per JEDEC JS-001;

Note4: CDM tested per JEDEC JS-002;

Note5: Latch up Current Maximum Rating tested per JEDEC JESD78F;

Recommended Operating Conditions

Symbol	Parameters	Rating	Unit
$V_{I/O}$	Input/Output Voltage	0 to 5.5	V
V_{CCB}	V_{REF_B} Supply Voltage	0 to 5.5	V
V_{REF_A} (V_{CCA})	Reference Voltage	0 to 5.5	V
V_{EN}	EN Pin Voltage	0 to 5.5	V
I_{PASS}	Pass Transistor Current	64	mA
T_A	Operating Ambient Temperature	-40 to +85	ºC

Electrical Characteristics

T_A = -40ºC~85ºC, from A to B or B to A (unless otherwise noted, all typical values are at T_A = 25°C.)

Symbol	Parameters	Conditions	Min	Typ	Max	Unit
V_{IK}	I/O Input Clamp Voltage	I_I = -18mA, V_{EN} = 0V			-1.2	V
I_{IH}	Input Leakage Current	V_I = 5V, V_{EN} = 0V		0.01	5.0	uA
I_{CC} (I_{CCA} + I_{CCB})	Input Current	V_{CCB} = V_{EN} = 5.5V, V_{CCA} = 4.5V, I_O = 0mA, V_I = V_{CC} or GND		0.01	5	uA
I_{CCBA}	Leakage from V_{CCB} to V_{CCA}	V_{CCB} = 3.3V, V_{CCA} = 1.2V, EN = 1.2V, I_O = 0, V_I = 3.3V or GND		11	15	uA
I_{off} (I_{CCA} + I_{CCB})	Shutdown Current	EN = Low		0.01	2	uA
$I_{Leakage}$	A Side	V_{CCA} and $I/O_{_A}$ = 0~5.5V, B Side Open		0.01	5	uA
	B Side	V_{CCB} and $I/O_{_B}$ = 0~5.5V, A Side Open		0.01	5	
$V_{IH(EN)}$	EN High	V_{CCA} = 0.95V ~ 3.3V	0.7* V_{CCA}			V
$V_{IL(EN)}$	EN Low	V_{CCA} = 0.95V ~ 3.3V			0.3* V_{CCA}	V
V_{OH}	High Level Output	V_{CCA} = 0.95V ~ 3.3V V_{CCB} = 1.62V ~ 5.0V	0.7* V_{CC}			V
V_{OL}	Low Level Output	V_{CCA} = 0.95V ~ 3.3V V_{CCB} = 1.62V ~ 5.0V			0.3* V_{CC}	V
$C_{I(REF_A/B/EN)}$ (6)	Input Capacitance	V_I = 3V or 0V， T_A = 25°C.		11		pF
$C_{IO(off)}$ (6)	Off Capacitance	V_I = 3V or 0V, V_{EN} = 0V, T_A = 25°C.		4.0	6.0	pF
$C_{IO(on)}$ (6)	On Capacitance	V_I = 3V or 0V, V_{EN} = 3V, T_A = 25°C.		12	15	pF

Electrical Characteristics(Continued)

T_A = -40ºC~85ºC, from A to B or B to A (unless otherwise noted, all typical values are at T_A = 25°C.)

Symbol	Parameters	Conditions		Min	Typ	Max	Unit
R_{ON}[7]	On-state Resistance EN = High	V_I = 0V, I_O = 64mA	V_{CCA} = 3.3V; V_{CCB} = 5V		3.0	7.0	Ω
			V_{CCA} = 1.8V; V_{CCB} = 5V		4.0	10	
			V_{CCA} = 1.0V; V_{CCB} = 5V		5.0	10	
		V_I = 0V, I_O = 32mA	V_{CCA} = 1.8V; V_{CCB} = 5V		4.0	9.0	
			V_{CCA} = 2.5V; V_{CCB} = 5V		3.0	8.0	
		V_I = 1.8V, I_O = 15mA	V_{CCA} = 3.3V; V_{CCB} = 5V		4.0	10	
		V_I = 1.0V, I_O = 10mA	V_{CCA} = 1.8V; V_{CCB} = 3.3V		7.0	10	
		V_I = 0V, I_O = 10mA	V_{CCA} = 1.0V; V_{CCB} = 3.3V		5.0	10	
		V_I = 0V, I_O = 10mA	V_{CCA} = 1.0V; V_{CCB} = 1.8V		6.0	10	
		V_I = 0V, I_O = 3mA	V_{CCA} = 1.8V; V_{CCB} = 3.3V		3.71	10	
			V_{CCA} = 1.2V; V_{CCB} = 3.3V		4.52	10	
			V_{CCA} = 1.2V; V_{CCB} = 1.8V		4.39	10	

Note6: Guaranteed by design and characterization, not a FT item.

Note7: Measured by the voltage drop between the A and B pins at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) pins.

AC Performance (Translating Down) Switching Characteristics

T_A=-40ºC~85ºC, from B to A, R_{UP} = 1KΩ (unless otherwise noted, all typical values are at T_A = 25°C.)

Symbol	Parameters	Conditions		Min	Typ	Max	Unit
t_{PLH}	Low-to-High Propagation Delay	V_{CCB} = V_{IH} = 1.8V, V_{CCA} = 0.95V, V_{IL} = 0V, and V_M = 0.5 V_{CCA}	C_L = 20pF		0.6	1.5	ns
			C_L = 30pF		0.8	2.0	
			C_L = 50pF		1.0	2.5	
		V_{CCB} = V_{IH} = 1.8V, V_{CCA} = 1.2V, V_{IL} = 0V, and V_M = 0.5 V_{CCA}	C_L = 20pF		0.8	1.5	
			C_L = 30pF		1.4	2.5	
			C_L = 50pF		3.0	4.0	
		V_{CCB} = V_{IH} = 3.3V, V_{CCA} = 1.8V, V_{IL} = 0V, and V_M = 0.5 V_{CCA}	C_L = 20pF		0.3	1.2	
			C_L = 30pF		0.5	2.0	
			C_L = 50pF		0.9	2.5	
		V_{CCB} = V_{IH} = 5V, V_{CCA} = 3.3V, V_{IL} = 0V, and V_M = 0.5 V_{CCA}	C_L = 20pF		0.8	1.2	
			C_L = 30pF		1.0	1.5	
			C_L = 50pF		1.2	2.0	
t_{PHL}	High-to-Low Propagation Delay	V_{CCB} = V_{IH} = 1.8V, V_{CCA} = 0.95V, V_{IL} = 0V, and V_M = 0.5 V_{CCA}	C_L = 20pF		0.4	2.5	
			C_L = 30pF		1.0	3.0	
			C_L = 50pF		2.0	4.0	
		V_{CCB} = V_{IH} = 1.8V, V_{CCA} = 1.2V, V_{IL} = 0V, and V_M = 0.5 V_{CCA}	C_L = 20pF		0.7	2.0	
			C_L = 30pF		1.3	3.0	
			C_L = 50pF		2.0	4.0	
		V_{CCB} = V_{IH} =3.3V, V_{CCA} = 1.8V, V_{IL} = 0V, and V_M = 0.5 V_{CCA}	C_L = 20pF		0.4	2.0	
			C_L = 30pF		0.9	2.5	
			C_L = 50pF		1.5	3.0	
		V_{CCB} = V_{IH} = 5V, V_{CCA} = 3.3V, V_{IL} = 0V, and V_M = 0.5 V_{CCA}	C_L = 20pF		0.4	1.5	
			C_L = 30pF		1.0	2.5	
			C_L = 50pF		1.4	3.0	
t_R	V_O Rising Time	Time from 0.1V_{CCO} to 0.9V_{CCO} R_{UP} = 220Ω	C_L = 50pF			10	ns
t_F	V_O Falling Time	Time from 0.9V_{CCO} to 0.1V_{CCO} R_{UP} = 220Ω	C_L = 50pF			15	ns
t_{sk}	Channel to Channel Skew		C_L = 20pF		0.2	0.5	ns
f_{MAX}	Transmission Frequency	R_{UP} = 100Ω	C_L = 30pF	40			MHz

AC Performance (Translating Up) Switching Characteristics

T_A = -40ºC~85ºC, from A to B, R_{UP} = 1KΩ (unless otherwise noted, all typical values are at T_A = 25°C.)

Symbol	Parameters	Conditions		Min	Typ	Max	Unit
t_{PLH}	Low-to-High Propagation Delay	V_{CCB} = 1.8V, V_{CCA} = V_{IH} = 0.95V, V_{IL} = 0V, and V_M = 0.5 V_{CCA}	C_L = 20pF		0.8	1.5	ns
			C_L = 30pF		1.0	2.0	
			C_L = 50pF		1.2	3.0	
		V_{CCB} = 1.8V, V_{CCA} = V_{IH} = 1.2V, V_{IL} = 0V, and V_M = 0.5 V_{CCA}	C_L = 20pF		1.1	1.5	
			C_L = 30pF		1.3	2.0	
			C_L = 50pF		1.9	3.0	
		V_{CCB} = 3.3V, V_{CCA} = V_{IH} = 1.8V, V_{IL} = 0V, and V_M = 0.5 V_{CCA}	C_L = 20pF		0.6	1.0	
			C_L = 30pF		0.8	1.5	
			C_L = 50pF		1.0	2.0	
		V_{CCB} = 5V, V_{CCA} = V_{IH} = 3.3V, V_{IL} = 0V, and V_M = 0.5 V_{CCA}	C_L = 20pF		0.6	1.5	
			C_L = 30pF		0.8	2.5	
			C_L = 50pF		1.2	3.0	
t_{PHL}	High-to-Low Propagation Delay	V_{CCB} =1.8V, V_{CCA} = V_{IH} = 0.95V, V_{IL} = 0V, and V_M = 0.5 V_{CCA}	C_L = 20pF		2.0	3.5	
			C_L = 30pF		2.8	4.5	
			C_L = 50pF		4.2	6.5	
		V_{CCB} = 1.8V, V_{CCA} = V_{IH} = 1.2V, V_{IL} = 0V, and V_M = 0.5 V_{CCA}	C_L = 20pF		1.7	3.0	
			C_L = 30pF		2.6	3.5	
			C_L = 50pF		4.2	4.5	
		V_{CCB} = 3.3V, V_{CCA} = V_{IH} = 1.8V, V_{IL} = 0V, and V_M = 0.5 V_{CCA}	C_L = 20pF		1.2	3.0	
			C_L = 30pF		1.8	4.0	
			C_L = 50pF		2.6	5.0	
		V_{CCB} = 5V, V_{CCA} = V_{IH} = 3.3V, V_{IL} = 0V, and V_M = 0.5 V_{CCA}	C_L = 20pF		0.8	2.0	
			C_L = 30pF		1.2	3.0	
			C_L = 50pF		1.8	4.0	
t_R	V_O Rising Time	Time from 0.1V_{CCO} to 0.9V_{CCO} R_{UP} = 220Ω	CL = 50pF			10	ns
t_F	V_O Falling Time	Time from 0.9V_{CCO} to 0.1V_{CCO} R_{UP} = 220Ω	CL = 50pF			15	ns
t_{sk}	Channel to Channel Skew		C_L = 50pF		0.2	0.5	ns
f_{MAX}	Transmission Frequency	R_{UP} = 100Ω	C_L = 30pF	40			MHz

AC Performance Test Circuit

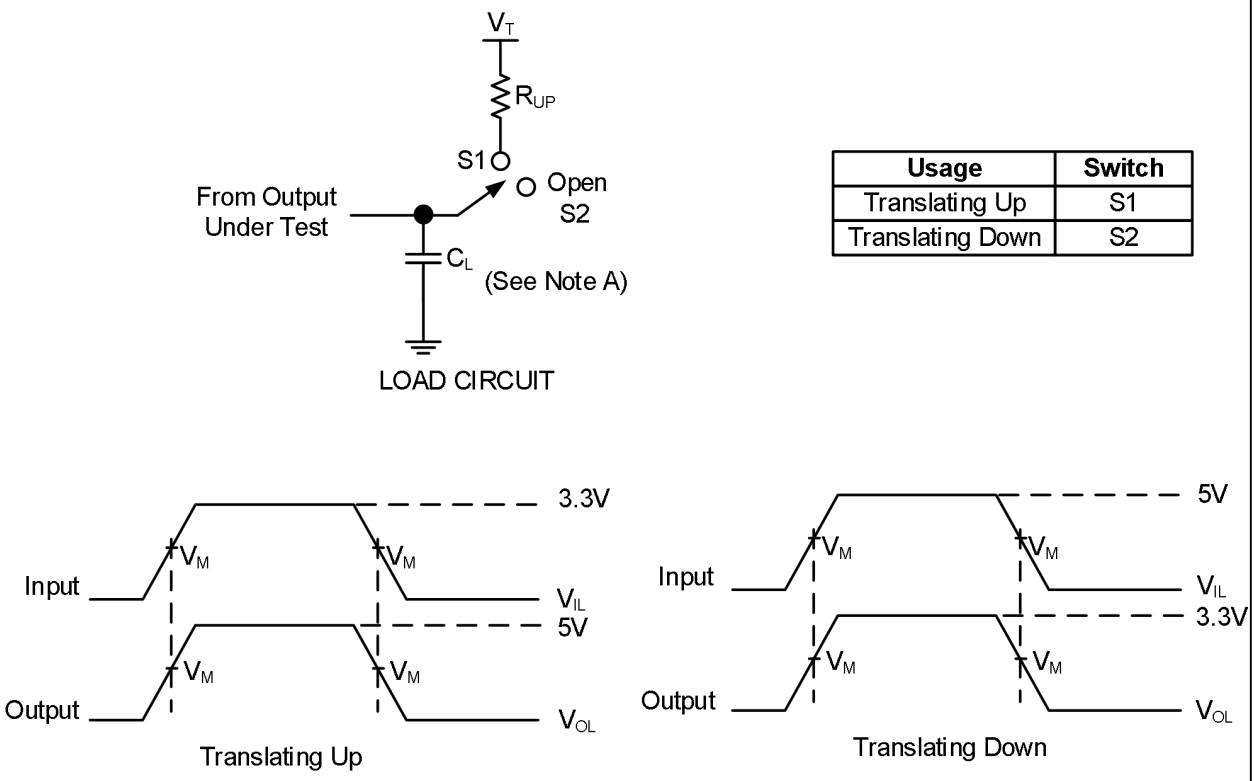


Figure 5. AC Performance Load Circuit for Outputs

Note A: C_L includes probe and jig capacitance.

Note B: Generators that have the following characteristics generate all input pulses: PRR ≤ 10MHz, Zo = 50Ω, tr ≤ 2ns, tf ≤ 2ns.

Note C: The outputs are measured one at a time, with one transition per measurement.

Application Circuits

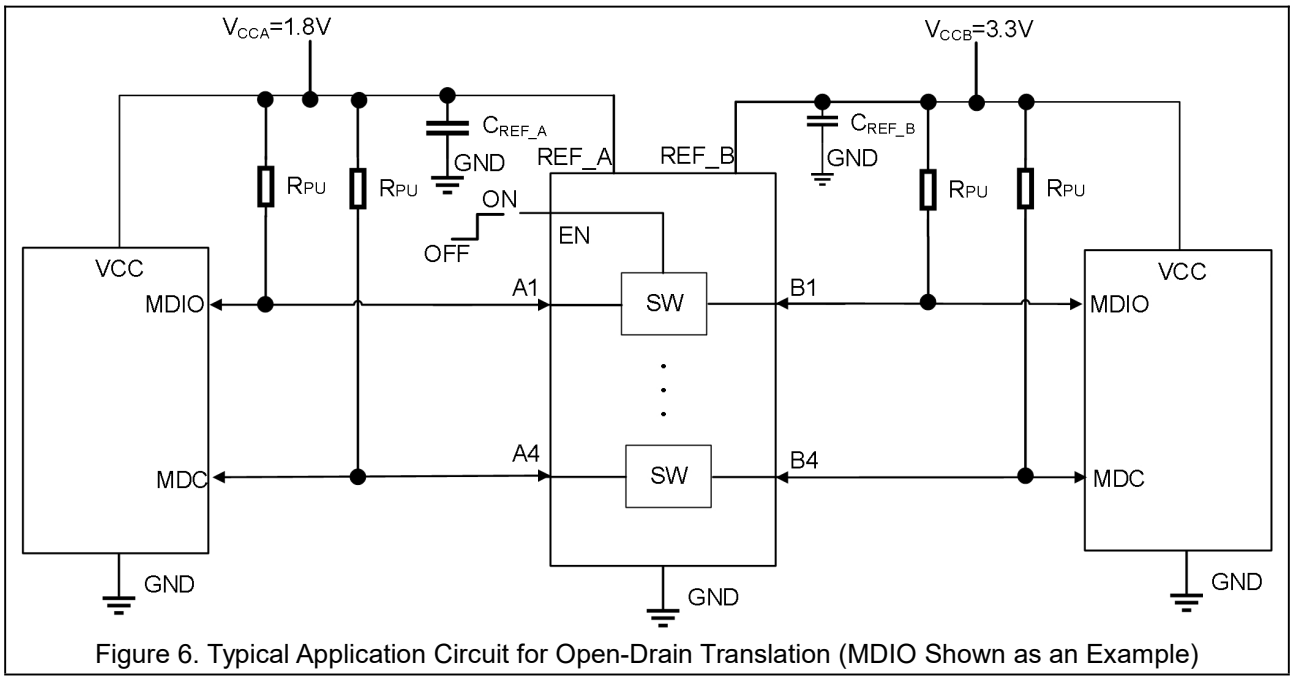


Figure 6. Typical Application Circuit for Open-Drain Translation (MDIO Shown as an Example)

In the previous figure, V_{CCB} is connected to a 3.3V power supply and V_{REF_A} is set to 1.8V. The A1 and A2 channels have a maximum output voltage equal to V_{REF_A} and the B1 and B2 channels have has a maximum output voltage equal to V_{PU}.

The ETF0104 has an EN input that is used to disable the device by setting EN LOW, placing all I/Os in the high-impedance state. Since the ETF0104 of devices are switch-type voltage translators, the power consumption is very low.

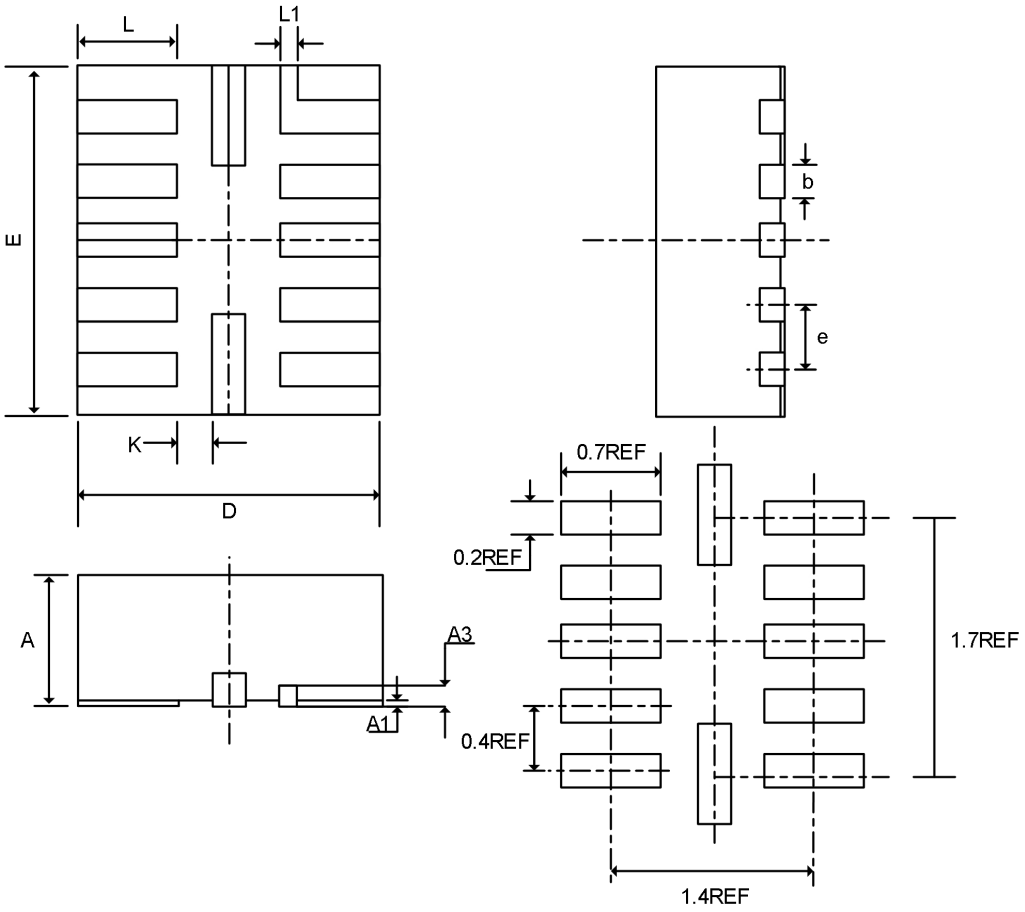
Table 3. Application Operating Condition

Symbol	Parameters	Min	Typ	Max	Unit
$V_{CCA}(V_{REF_A})$ (8)	Reference Voltage (A)	0.9		5.5	V
V_{CCB}	V_{REF_B} Supply Voltage (B)	V_{CCA} + 0.8		5.5	V
V_{EN}	Input Voltage on EN Pin	0		5.5	V
V_{PU}	Pull-up Supply Voltage	0		V_{CCB}	V

Note8: $V_{CCA}(V_{REF_A})$ is required to be the lowest voltage level across all inputs and outputs.

Package Dimension

QFN12 (2.0mm × 1.7mm)

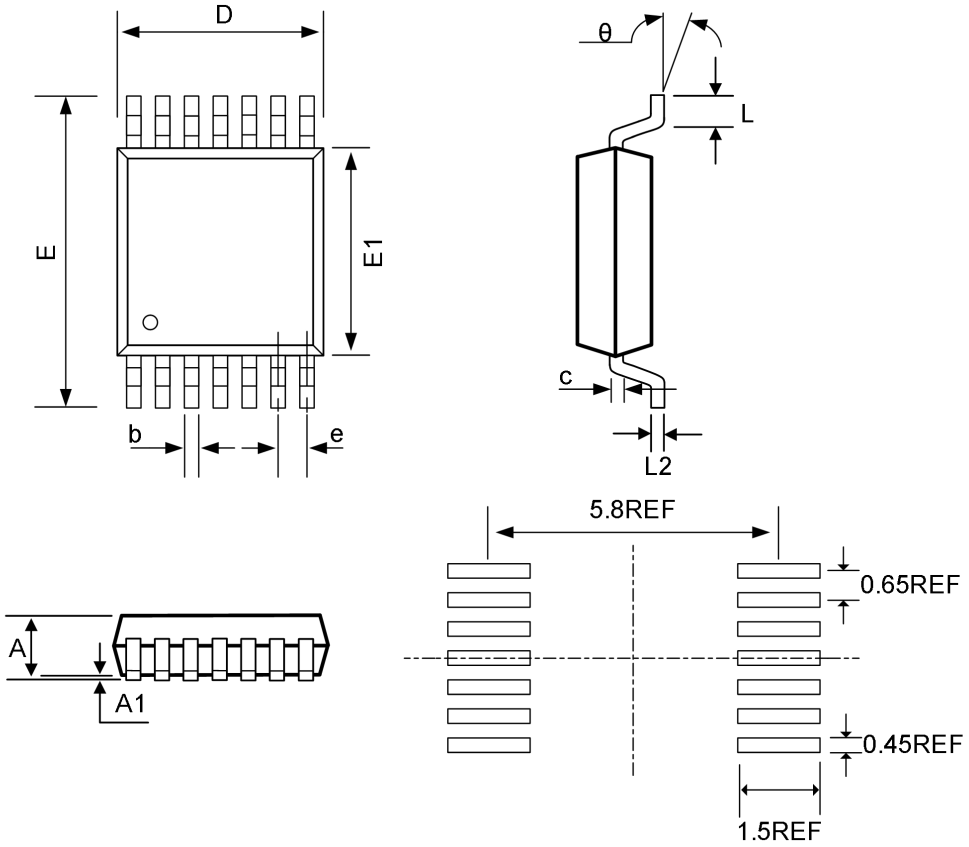


COMMON DIMENSIONS

(Unit: mm)

Symbol	Min	Max
A	0.450	0.550
A1	0.000	0.050
A3	0.152 REF.	
b	0.150	0.250
D	1.600	1.800
E	1.900	2.100
e	0.400 TYP.	
L	0.450	0.550
L1	0.150 REF.	
K	0.200 MIN.	

TSSOP14 (5.0mm × 4.4mm)

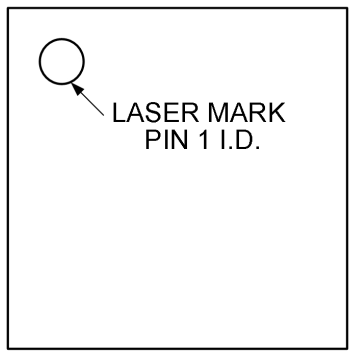


COMMON DIMENSIONS

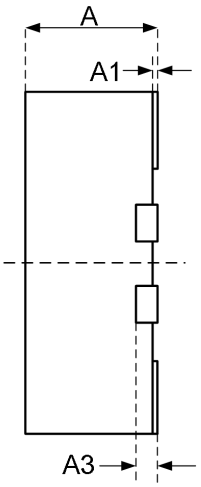
(Unit: mm)

Symbol	Min	Max
A	--	1.20
A1	0.05	0.15
b	0.19	0.30
c	0.15 REF	
D	4.90	5.10
E	6.20	6.60
E1	4.30	4.50
e	0.65BSC	
L	0.50	0.72
L2	0.25 REF	
θ	0°	8°

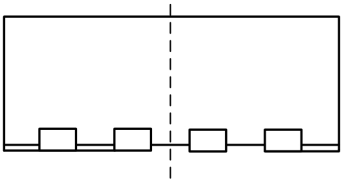
QFN12 (1.6mm × 1.6mm)



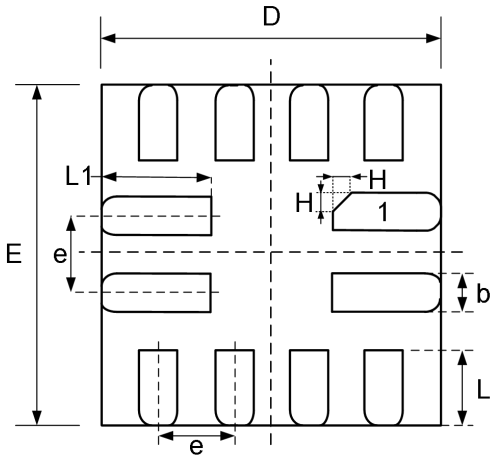
TOP VIEW



SIDE VIEW



SIDE VIEW



BOTTOM VIEW

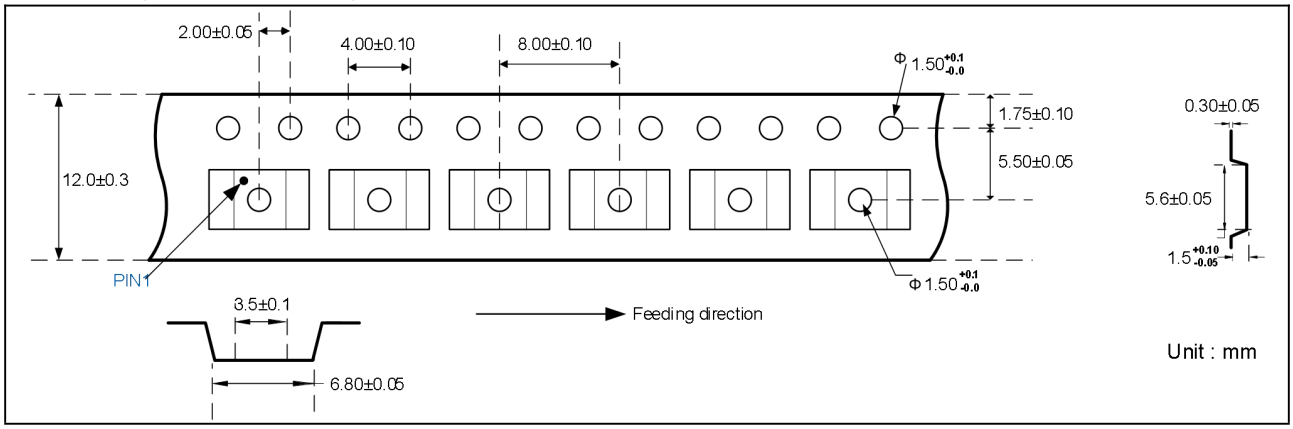
COMMON DIMENSIONS

(Unit: mm)

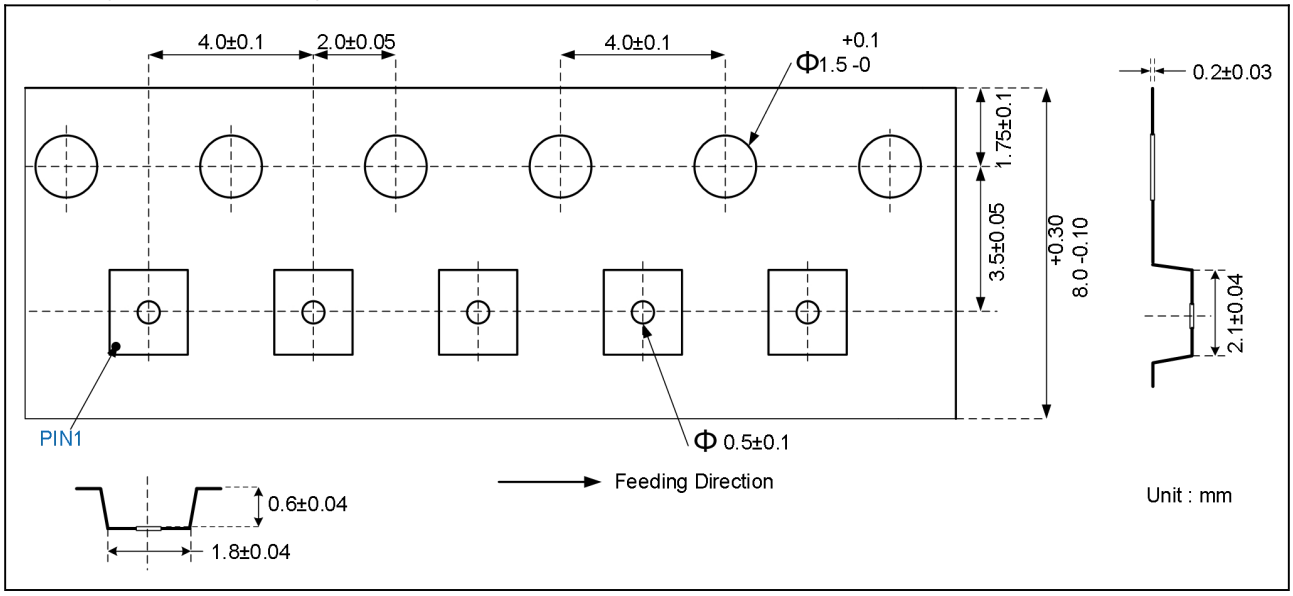
Symbol	Min	Nom	Max
A	0.50	0.55	0.60
A1	0.00	0.02	0.05
A3		0.127 REF	
D	1.55	1.60	1.65
E	1.55	1.60	1.65
b	0.15	0.20	0.25
L	0.25	0.30	0.35
L1	0.45	0.50	0.55
H		0.10 REF	
e	0.35	0.40	0.45

Tape Information

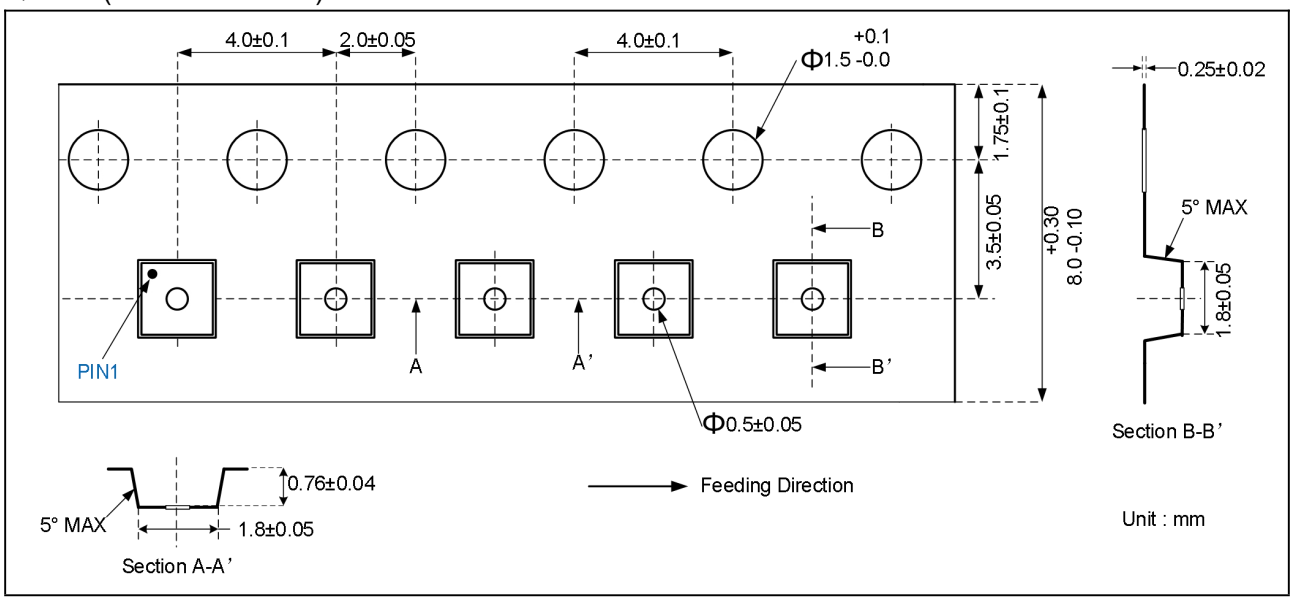
TSSOP14 (5.0mm × 4.4mm)



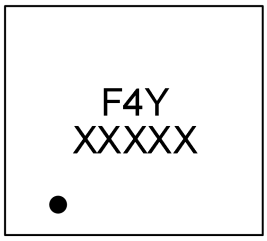
QFN12 (2.0mm × 1.7mm)



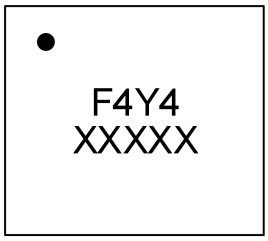
QFN12 (1.6mm × 1.6mm)



Marking Information



ETF0104Y1
F4Y = Part Number
XXXXX = Tracking Number



ETF0104Y4
F4Y4 = Part Number
XXXXX = Tracking Number

Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
0.0	2025.05.22	Preliminary Version	Zhang Wang	Yang Xiao Xu	Liu Jia Ying
0.0.a	2025-10-13	Words Correction	Zhang Wang	Liu Yi Guo	Liu Jia Ying
0.1	2026.01.27	Preliminary Version	Yang Xiao Xu	Yang Xiao Xu	Liu Jia Ying
1.0	2026.08.18	Official Version	Lu Shao Jie	Yang Xiao Xu	Liu Jia Ying
1.1	2026.08.20	Add QFN12(1.6*1.6) Package	Lu Shao Jie	Yang Xiao Xu	Liu Jia Ying
1.2	2026.09.01	Update Marking Information	Lu Shao Jie	Yang Xiao Xu	Liu Jia Ying
1.3	2026.10.21	Update Format	Lu Shao Jie	Yang Xiao Xu	Liu Jia Ying